Infineon Technologies - SAF-XC878-13FFI 3V3 AA Datasheet

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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	XC800
Core Size	8-Bit
Speed	27MHz
Connectivity	SPI, SSI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	40
Program Memory Size	52KB (52K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	3.25K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 3.6V
Data Converters	A/D 8x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	PG-LQFP-64-4
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/saf-xc878-13ffi-3v3-aa

3.3 Flash Memory

The Flash memory provides an embedded user-programmable non-volatile memory, allowing fast and reliable storage of user code and data. It is operated from a single 2.5 V supply from the Embedded Voltage Regulator (EVR) and does not require additional programming or erasing voltage. The pagination of the Flash memory allows each page to be erased independently.

Features

- In-System Programming (ISP) via UART
- In-Application Programming (IAP)
- Error Correction Code (ECC) for dynamic correction of single-bit errors
- Background program and erase operations for CPU load minimization
- Support for aborting erase operation
- Minimum program width
- of 1-byte for D-Flash and 2-bytes for P-Flash
- 1-page minimum erase width
- 1-byte read access
- Flash is delivered in erased state (read all ones)
- Operating supply voltage: 2.5 V ± 7.5 %
- Read access time: 1 × t_{CCLK} = 38 ns[1)]
- Program time for 1 wordline: 1.6 ms[2)]
- Page erase time: 20 ms
- Mass erase time: 200 ms

1) Values shown here are typical values. f_{sys} = 144 MHz ± 7.5% (f_{CCLK} = 24 MHz ± 7.5 %) is the maximum frequency range for Flash read access.

2) Values shown here are typical values. f_{sys} = 144 MHz ± 7.5% (f_{CCLK} = 24 MHz ± 7.5 %) is the typical frequency range for Flash programming and erasing. f_{sysmin} is used for obtaining the worst case timing.

Table 20 and **Table 21** shows the Flash data retention and endurance targets for Industrial profile and Automotive profile respectively.

Table 20 Flash Data Retention and Endurance for Industrial Profile (Operating Conditions apply)

Retention	Endurance[1)2)]	Size	Remarks
Program Flash			
15 years	1000 cycles	up to 60 Kbytes	
Data Flash			
15 years	1000 cycles	4 Kbytes	
10 years	10,000 cycles	4 Kbytes	
5 years	30,000 cycles	4 Kbytes	
1 year	100,000 cycles	4 Kbytes	SAF and SAX variant
	80,000 cycles		SAK variant

1) In Program Flash, one cycle refers to the programming of all pages in the flash bank and a mass erase.

2) In Data Flash, one cycle refers to the programming of all wordlines in a page and a page erase.

Table 21 Flash Data Retention and Endurance for Automotive Profile (Operating Conditions apply)

Retention	Endurance[1)2)]	Size	Remarks
Program Flash			
15 years	1000 cycles	up to 60 Kbytes	
Data Flash			
15 years	1000 cycles	4 Kbytes	
5 years	10,000 cycles	1 Kbytes	
2 years	15,000 cycles	512 Bytes	
2 years	30,000 cycles	256 Bytes	
1 year	100,000 cycles	128 Bytes	

1) In Program Flash, one cycle refers to the programming of all pages in the flash bank and a mass erase.

2) In Data Flash, one cycle refers to the programming of all wordlines in a page and a page erase.

Table 32 Deviation Error for UART wi th Fractional Divider enabled

f_{PCLK}	Prescaling Factor (2BRPRE)	Reload Value (BR_VALUE + 1)	STEP	Deviation Error
24 MHz	1	6 (6_H)	59 ($3B_H$)	+0.03 %
12 MHz	1	3 (3_H)	59 ($3B_H$)	+0.03 %
8 MHz	1	2 (2_H)	59 ($3B_H$)	+0.03 %
6 MHz	1	6 (6_H)	236 (EC_H)	+0.03 %

3.13.2 Baud Rate Generation using Timer 1

In UART modes 1 and 3 of UART module, Timer 1 can be used for generating the variable baud rates. In theory, this timer could be used in any of its modes. But in practice, it should be set into auto-reload mode (Timer 1 mode 2), with its high byte set to the appropriate value for the required baud rate. The baud rate is determined by the Timer 1 overflow rate and the value of SMOD as follows:

$$\text{Mode 1, 3 baud rate} = \frac{2^{SMOD} \times f_{PCLK}}{32 \times 2 \times (256 - TH1)} \tag{3.6}$$

3.14 Normal Divider Mode (8-bit Auto-reload Timer)

Setting bit FDM in register FDCON to 1 configures the fractional divider to normal divider mode, while at the same time disables baud rate generation (see Figure 26). Once the fractional divider is enabled (FDEN = 1), it functions as an 8-bit auto-reload timer (with no relation to baud rate generation) and counts up from the reload value with each input clock pulse. Bit field RESULT in register FDRES represents the timer value, while bit field STEP in register FDSTEP defines the reload value. At each timer overflow, an overflow flag (FDCON.NDOV) will be set and an interrupt request generated. This gives an output clock f_{MOD} that is 1/n of the input clock f_{DIV}, where n is defined by 256 - STEP.

The output frequency in normal divider mode is derived as follows:

$$f_{MOD} = f_{DIV} \times \frac{1}{256 - STEP} \tag{3.7}$$

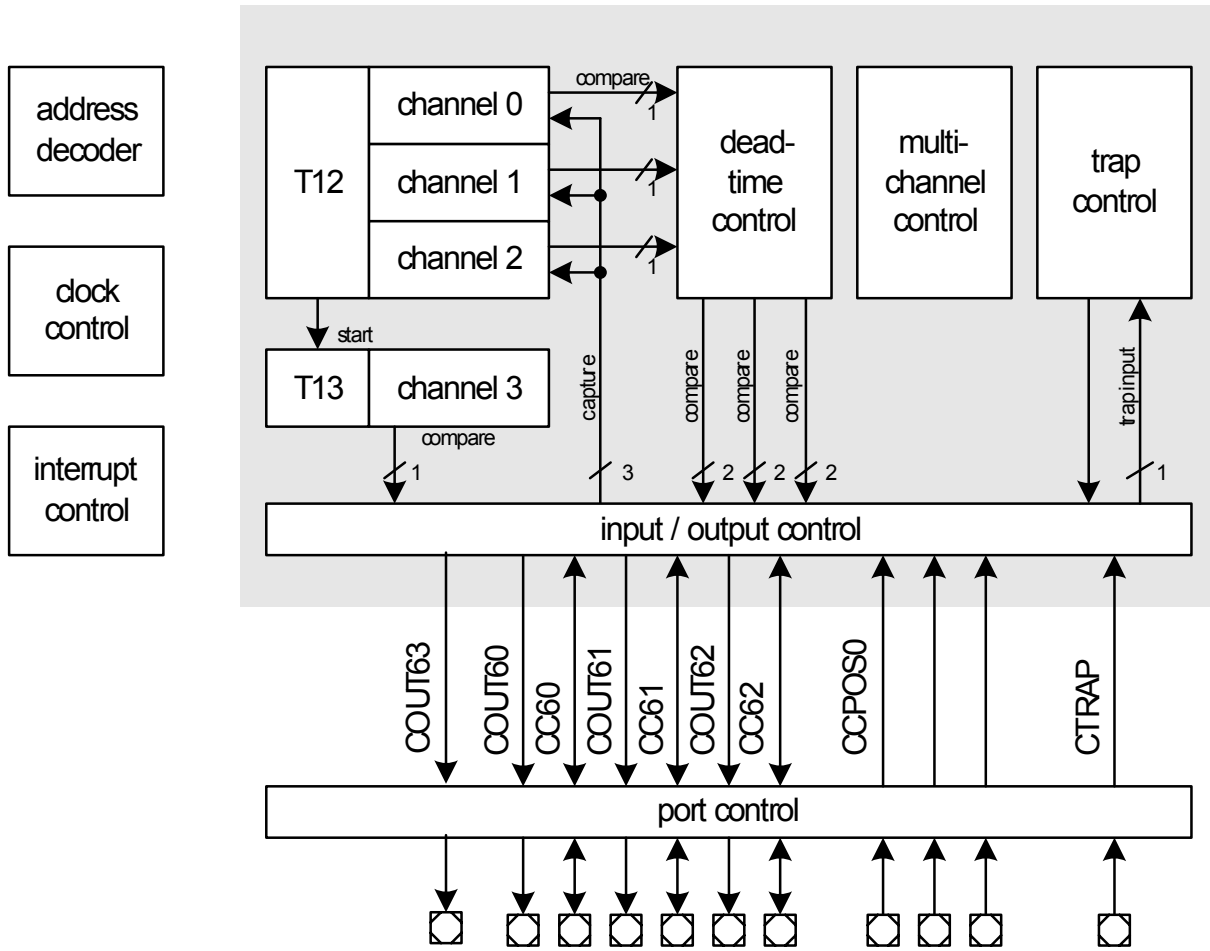

Figure 29 CCU6 Block Diagram

- Synchronization phase (t_{SYN})
- Sample phase (t_S)
- Conversion phase
- Write result phase (t_{WR})

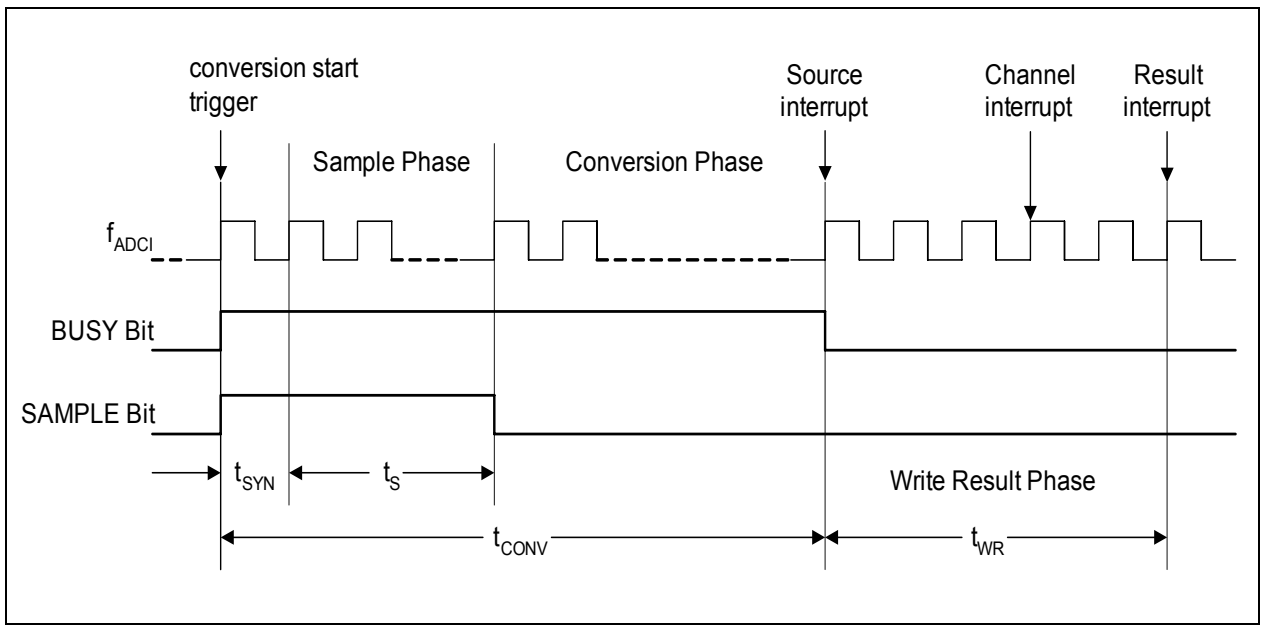

Figure 32 ADC Conversion Timing

4.2.2 Supply Threshold Characteristics

Table 41 provides the characteristics of the supply threshold in the XC87x.

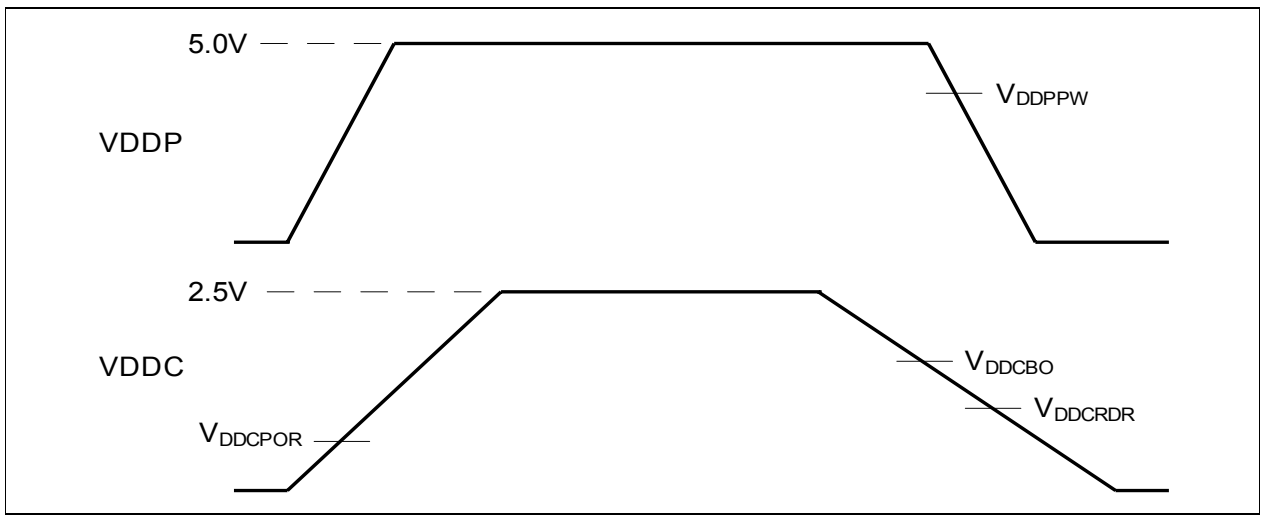

Figure 34 Supply Threshold Parameters

Table 41 Supply Threshold Parameters (Operating Conditions apply)

Parameters	Symbol		Limit Values			Unit
			min.	typ.	max.	
V_{DDC} brownout voltage[1)]	V_{DDCBO}	CC	1.7	1.9	2.2	V
RAM data retention voltage	V_{DDCRDR}	CC	1.2	–	–	V
V_{DDP} prewarning voltage[2)]	V_{DDPPW}	CC	3.8	4.2	4.5	V
Power-on reset voltage[1)3)]	V_{DDCPOR}	CC	1.7	1.9	2.2	V

1) Detection is enabled in both active and power-down mode.

2) Detection is enabled for 5.0V power supply variant.
Detection is disabled for 3.3V power supply variant.

3) The reset of EVR is extended by 300 µs typically after the VDDC reaches the power-on reset voltage.